NSN 5961-00-761-3864

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-761-3864
Inclosure Material:
Metal
Overall Length:
0.425 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.437 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 working peak reverse voltage, peak total value, gate terminal open-circuited
Current Rating Per Characteristic:
100.00 amperes source cutoff current absolute
Power Rating Per Characteristic:
20.0 watts small-signal input power, common-collector outside diameter
Maximum Operating Tempurature Per Measurement Point:
105.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0